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APPLICATION NO.	ICATION NO. FILING DATE FIRST NAMED INVENTOR		ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/796,963 03/11/2004		Nobutoshi Arai	0020-5237P	4006	
2292	7590 12/02/2004		EXAMINER		
BIRCH ST	EWART KOLASCH	SEFER, A	SEFER, AHMED N		
PO BOX 74 FALLS CHI	7 JRCH, VA 22040-074	ART UNIT	PAPER NUMBER		
	, , , , , , , , , , , , , , , , , , ,	,	2826		
			DATE MAILED: 12/02/2004		

Please find below and/or attached an Office communication concerning this application or proceeding.

	Appl		Application No. Applicant(s)						
Office Action Summary		10/796,9	63	ARAI ET AL.					
		Examine		Art Unit					
		A. Sefer		2826	l A				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address									
Period for Reply									
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).									
Status									
1)⊠	Responsive to communication(s) filed on 28	October 200	4.						
'=									
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is								
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.								
Disposition of Claims									
4)⊠	Claim(s) 1-23 is/are pending in the application	nn .							
· ·	4a) Of the above claim(s) <u>9-20</u> is/are withdrawn from consideration.								
	☐ Claim(s) is/are allowed.								
· · ·	Claim(s) <u>1-8 and 21-23</u> is/are rejected.								
· · · · · · · · · · · · · · · · · · ·	Claim(s) is/are objected to.								
· · · · · · · · · · · · · · · · · · ·	Claim(s) are subject to restriction and/or election requirement.								
Applicat	ion Papers								
_	The specification is objected to by the Exami	ner							
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.									
,	Applicant may not request that any objection to the	-	•						
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).								
11)	The oath or declaration is objected to by the	-		-					
Priority ı	under 35 U.S.C. § 119								
_	•	an nriarity un	dor 35 II S C & 110/a) (d) or (f)					
12)⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).									
u)	a)⊠ All b)⊡ Some * c)⊡ None of: 1.⊠ Certified copies of the priority documents have been received.								
	<u> </u>			ion No					
	 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage 								
	application from the International Bure	-			· cage				
* See the attached detailed Office action for a list of the certified copies not received.									
• • •					•				
Attachmen			4) Dinton down Surrence	. (PTO 442)	•				
1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) Paper No(s)/Mail Date									
3) 🛛 Infon	mation Disclosure Statement(s) (PTO-1449 or PTO/SB/0er No(s)/Mail Date <u>3/2004</u> .	08)	5) Notice of Informal I		O-152)				

DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of Group I (claims 1-8 and 21-23) in the reply filed on 10/28/2004 is acknowledged.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1-9 are rejected under 35 U.S.C. 102(b) as being anticipated by Iwata et al. ("Iwata") (JP 2002-252290).

Iwata discloses (figs. 1C, 1D, 2, 10-13 and par. 0165 of equivalent US PG-Pub 2004-0115883) a memory function body comprising: a first conductor 111 or silicon substrate (as in claim 8) and a second conductor 116; a medium 112 that is formed between the first conductor and the second conductor and made of a first material; and at least one particle 114 that is formed in the medium, covered with a second material (par. 0155), and made of a third material, the second material being a material that functions as a barrier against passage of electric charges, and the third material being a material that has a function to retain electric charges.

As for claim 2, Iwata discloses the first material and the second material being different insulators, and the third material is a conductor.

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As for claims 3 and 4, Iwata discloses (par. 0155) the second material being a material obtained by making the third material insulative obtained by oxidizing or nitriding the third material (as in claim 4).

As for claims 5-7, Iwata discloses the first material being a silicon oxide or a silicon nitride (par. 0165), the second material is a semiconductor oxide or a metal oxide aluminum oxide, and the third material is a semiconductor or a metal (par. 0165) or aluminum (as in claims 6 and 7).

4. Claims 21-23 are rejected under 35 U.S.C. 102(b) as being anticipated by Iwata.

Iwata discloses (figs. 1C, 1D, 2, 10-13 and par. 0165 of equivalent US PG-Pub 2004-0115883) a memory device or a memory circuit having memory devices (as in claim 22) or Electronic equipment including a semiconductor device including a memory circuit having memory devices (as in claim 23) including a field-effect type transistor that employs a memory function body comprising a first conductor 111 and a second conductor 116; a medium 112 that is formed between the first conductor and the second conductor and made of a first material; and at least one particle 114 that is formed in the medium, covered with a second material (par. 0155), and made of a third material, the second material being a material that functions as a barrier against passage of electric charges, and the third material being a material that has a function to retain electric charges.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to A. Sefer whose telephone number is (571) 272-1921

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915.

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ANS November 19, 2004

SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800